

Product Summary

$V_{(BR)DSS}$	$R_{DS(ON)}$	I_D $T_A = +25^\circ\text{C}$
200V	10Ω @ $V_{GS} = 10\text{V}$	320mA

Description

This new generation trench MOSFET features a unique structure combining the benefits of low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

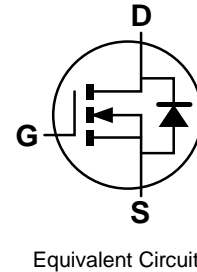
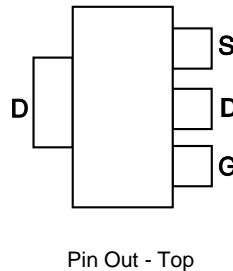
- Off-line Power Supply Start-up Circuitry

Features and Benefits

- High Voltage
- Low On-resistance
- Fast Switching Speed
- Low Gate Drive
- Low Threshold
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**
- Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.112 grams (Approximate)

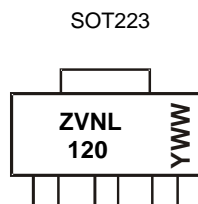


Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVNL120GTA	ZVNL120	7	12	1,000
ZVNL120GTC	ZVNL120	13	12	4,000

- Notes:
- EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 - See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



ZVNL120 = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 5 = 2015)
 WW or $\bar{W}W$ = Week Code (01~53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	200	V
Gate-Source Voltage	V _{GSS}	±20	V
Continuous Drain Current (V _{GS} = 10V, T _A = +25°C)	I _D	320	mA
Pulsed Drain Current	I _{DM}	2	A

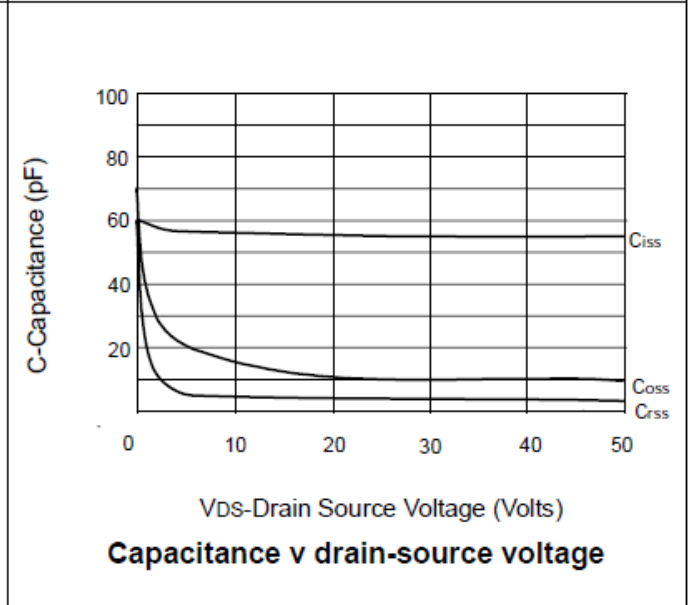
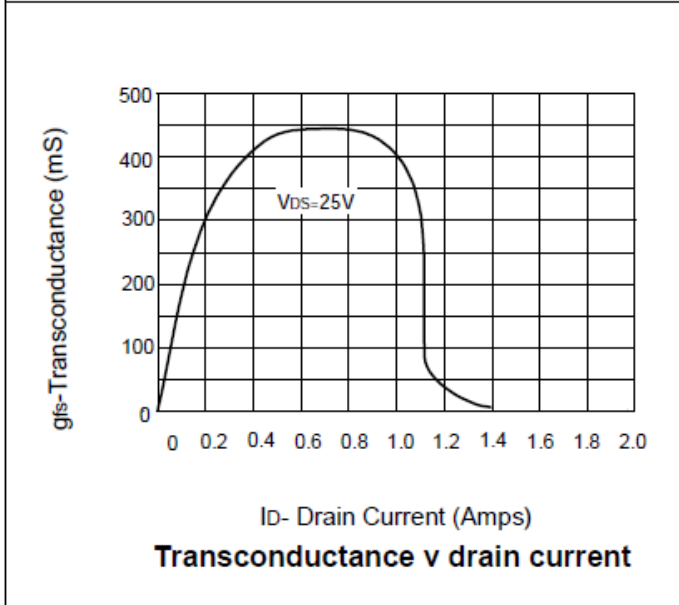
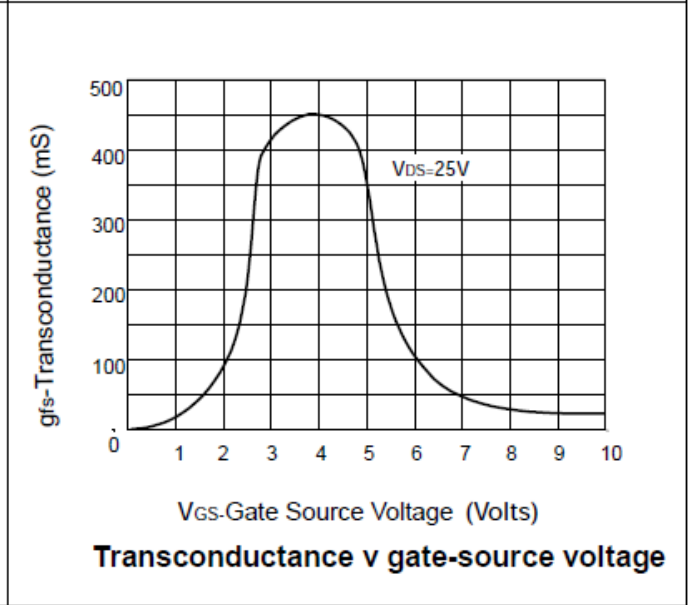
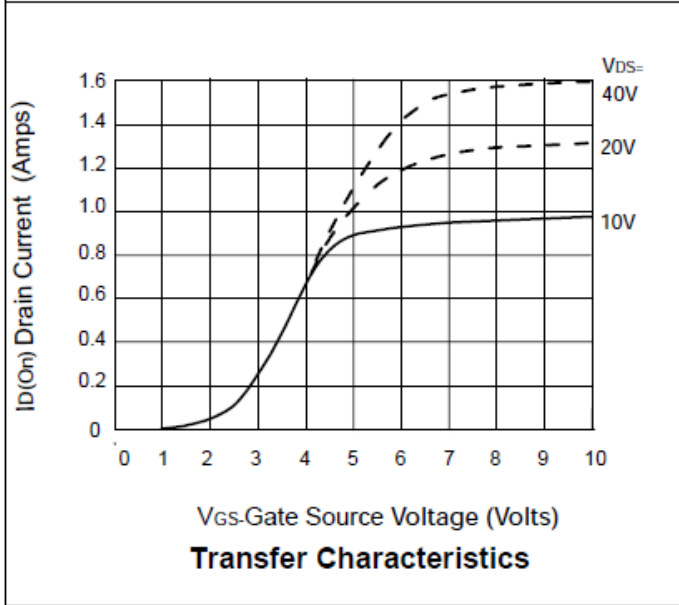
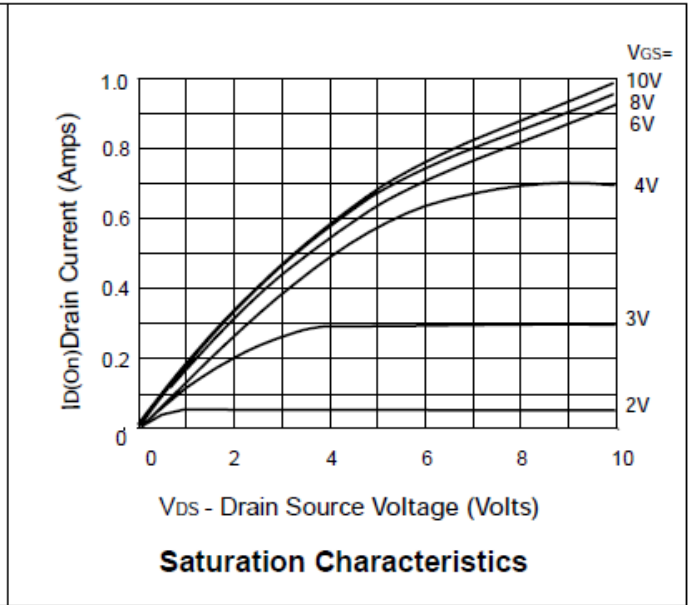
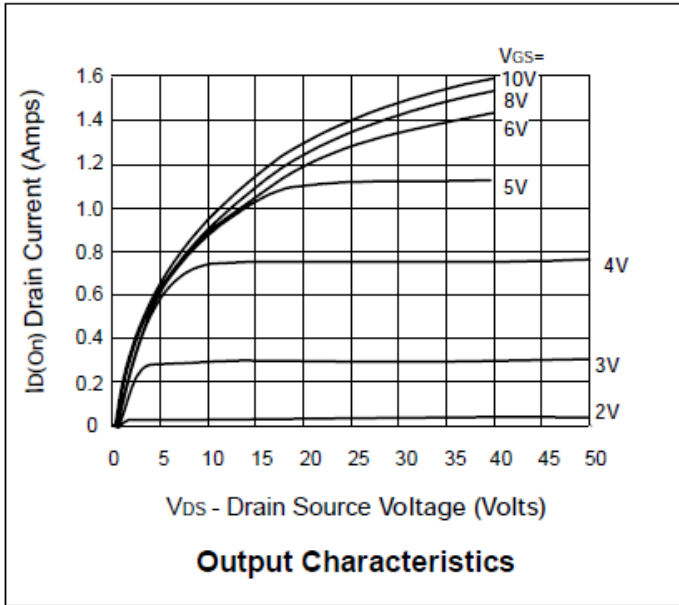
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

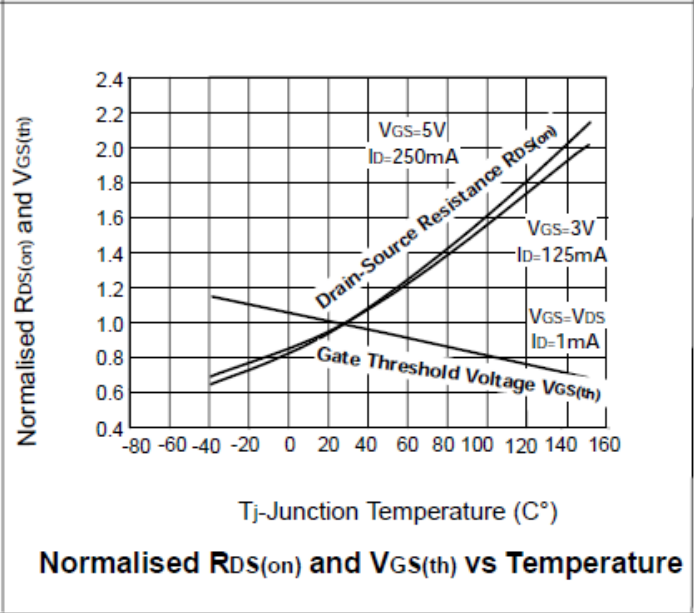
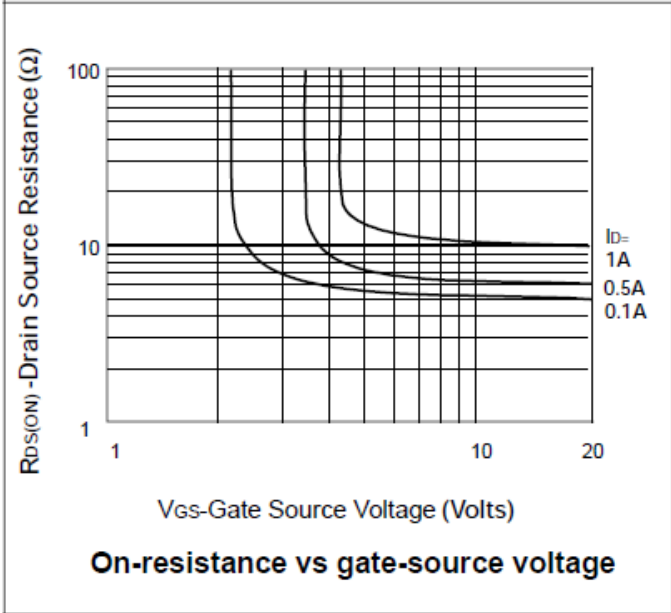
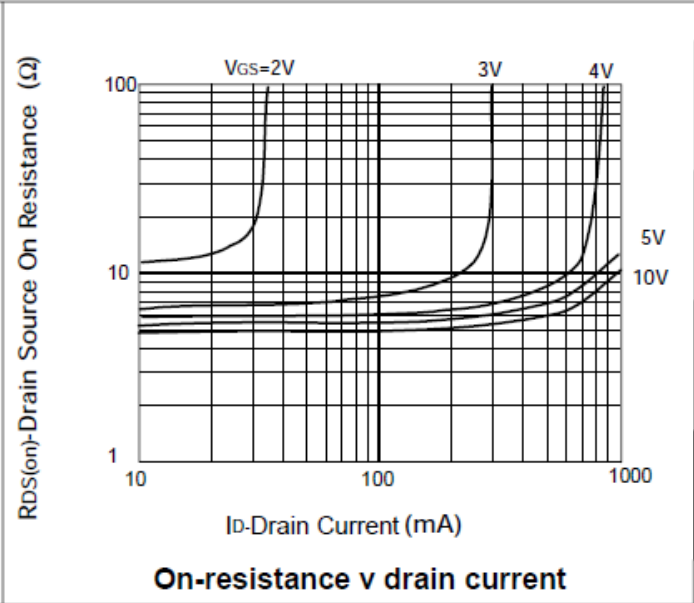
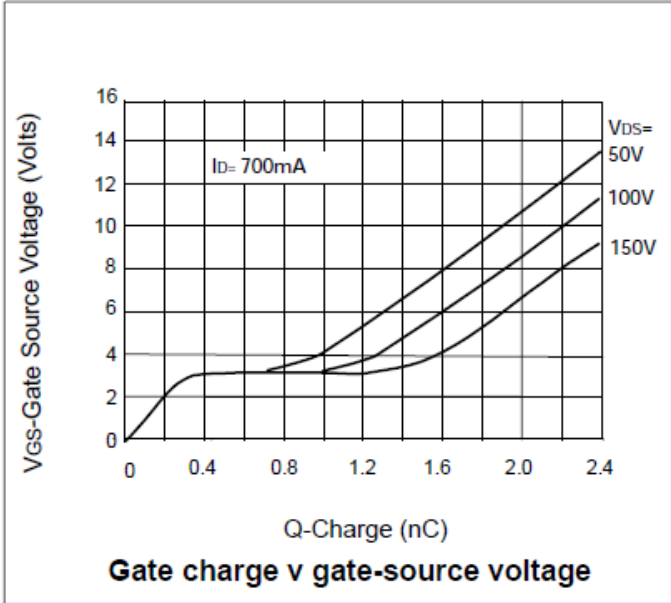
Characteristic	Symbol	Value	Unit
Power Dissipation at T _A = +25°C (Note 5)	P _D	2.0	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	200	-	-	V	V _{GS} = 0V, I _D = 1mA
Zero Gate Voltage Drain Current	I _{DSS}	-	-	10 100	μA	V _{DS} = 200V, V _{GS} = 0V V _{DS} = 160V, V _{GS} = 0V, T = +125°C
Gate-Source Leakage	I _{GSS}	-	-	100	nA	V _{GS} = ±20V, V _{DS} = 0V
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	0.5	-	1.5	V	V _{DS} = V _{GS} , I _D = 1mA
Static Drain-Source On-Resistance (Note 6)	R _{DS(ON)}	-	-	10	Ω	V _{GS} = 5V, I _D = 250mA
		-	-	10	Ω	V _{GS} = 3V, I _D = 125mA
Forward Transconductance (Notes 6 & 7)	g _{fs}	200	-	-	mS	V _{DS} = 25V, I _D = 250mA
On-State Drain Current (Note 6)	I _{D(ON)}	500	-	-	mA	V _{DS} = 25V, V _{GS} = 5V
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C _{iss}	-	-	85	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	-	-	20	pF	
Reverse Transfer Capacitance	C _{rss}	-	-	7	pF	
Turn-On Delay Time (Note 8)	t _{D(ON)}	-	-	8	ns	V _{DD} = 25V, I _D = 250mA
Turn-On Rise Time (Note 8)	t _R	-	-	8	ns	
Turn-Off Delay Time (Note 8)	t _{D(OFF)}	-	-	20	ns	
Turn-Off Fall Time (Note 8)	t _F	-	-	12	ns	

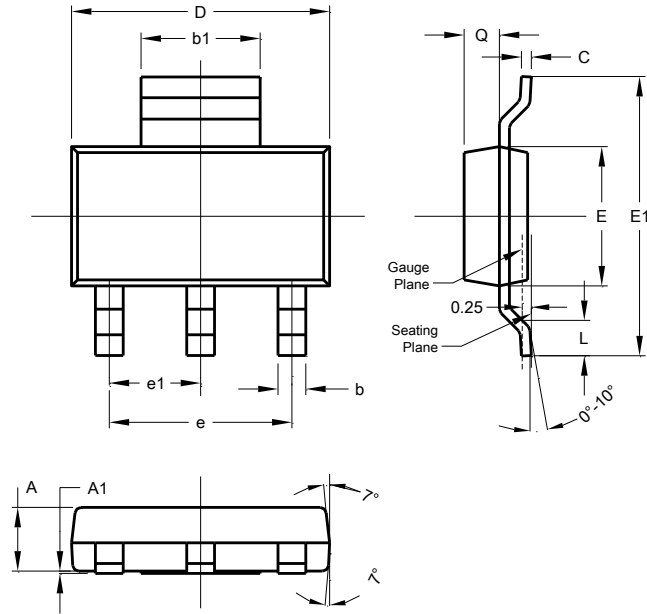
- Notes:
5. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 6. Measured under pulsed conditions. Pulse width ≅ 300μs. Duty cycle ≅ 2%.
 7. Sample test.
 8. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.





Package Outline Dimensions

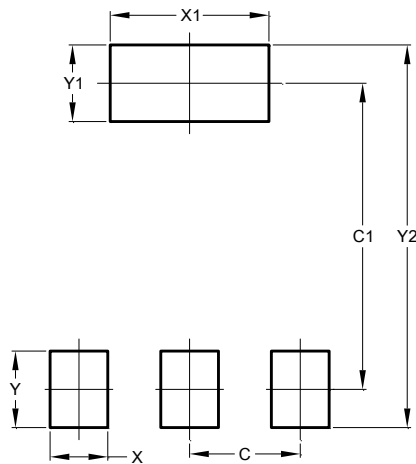
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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